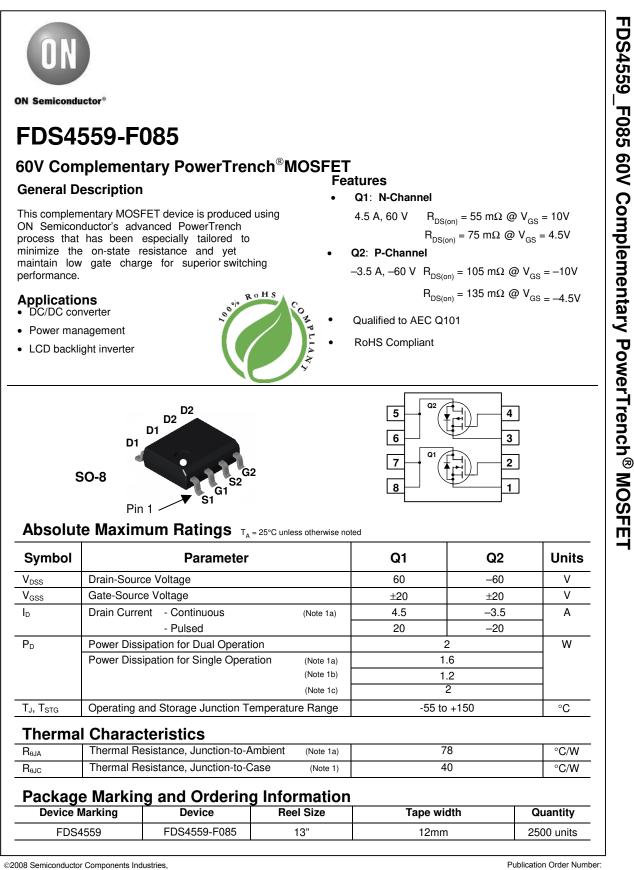
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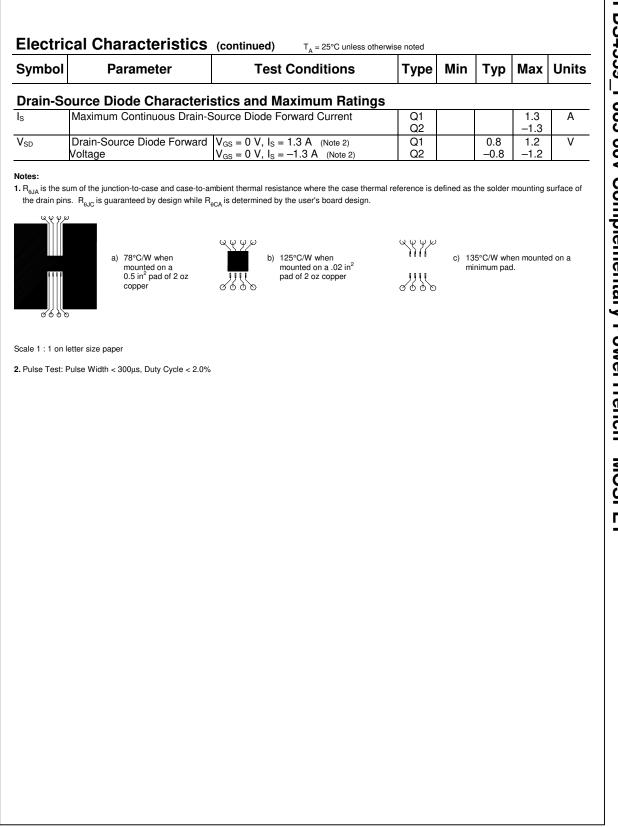
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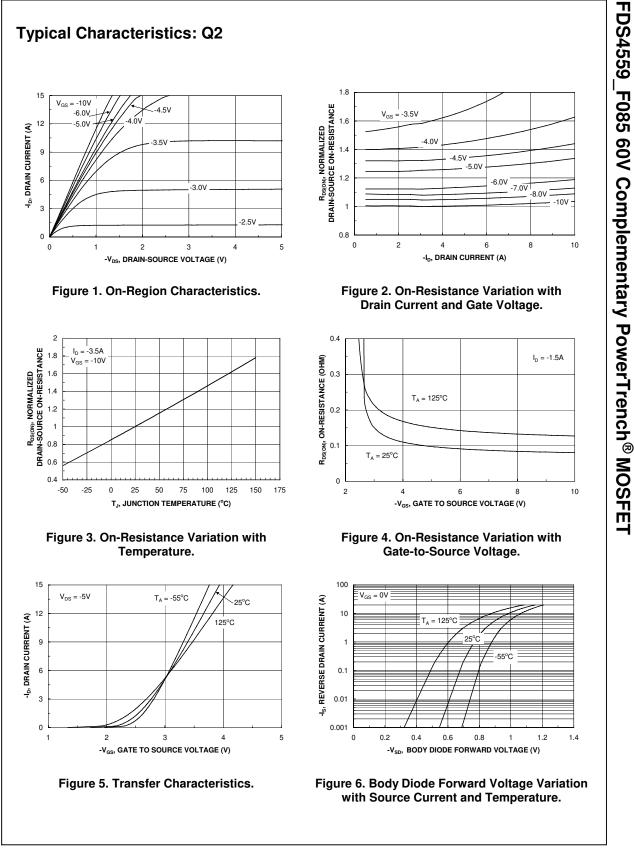
Symbol	Parameter	Test Conditions	Туре	Min	Тур	Мах	Units
Drain-Se	ource Avalanche Rating	<b>]S</b> (Note 1)					
W <sub>DSS</sub>	Single Pulse Drain-Source Avalanche Energy	$V_{DD} = 30 \text{ V}, \qquad I_D = 4.5 \text{ A}$	Q1			90	mJ
I <sub>AR</sub>	Maximum Drain-Source Avalanche Current		Q1			4.5	A
Off Cha	racteristics	-					
BV <sub>DSS</sub>	Drain-Source Breakdown	$V_{GS} = 0 V, I_D = 250 \mu A$	Q1	60			V
	Voltage Breakdown Voltage	$V_{GS} = 0 V, I_D = -250 \mu A$	Q2 Q1	-60	58		
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to 25°C $I_D = -250 \ \mu$ A, Referenced to 25°C	Q2		-49		mV/°C
	Zero Gate Voltage Drain	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}$	Q1			1	μA
	Current	$V_{DS} = -48 \text{ V}, V_{GS} = 0 \text{ V}$	Q2			-1	
I <sub>GSS</sub>	Gate-Body Leakage	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	Q1 Q2			<u>+</u> 100 +100	nA
<u> </u>		$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	Q2			<u>+</u> 100	
	racteristics (Note 2)				0.0		
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$ $V_{DS} = V_{GS}, I_D = -250 \ \mu A$	Q1 Q2	1 -1	2.2 -1.6	3 3	V
$\Delta V_{GS(th)}$	Gate Threshold Voltage	$I_D = 250 \ \mu\text{A}$ , Referenced to 25°C	Q1		-5.5	Ŭ	mV/°C
$\Delta T_{\rm J}$	Temperature Coefficient	$I_D = -250 \ \mu A$ , Referenced to $25^{\circ}C$	Q2		4		
	Static Drain-Source	$V_{GS} = 10 \text{ V}, I_D = 4.5 \text{ A}$	Q1		42	55	mΩ
	On-Resistance				72 55	94 75	
		$V_{GS} = 4.3 V, I_D = 4 A$ $V_{GS} = -10 V, I_D = -3.5 A$	Q2		82	105	_
		$V_{GS} = -10 \text{ V}, \text{ I}_D = -3.5 \text{ A}, \text{ T}_J = 125^{\circ}\text{C}$	~_		130	190	
		$V_{GS} = -4.5 \text{ V}, I_D = -3.1 \text{ A}$ $V_{GS} = 10 \text{ V}, V_{DS} = 5 \text{ V}$			105	135	
I <sub>D(on)</sub>	On-State Drain Current	$V_{GS} = 10 \text{ V}, V_{DS} = 5 \text{ V}$	Q1 Q2	20 –20			A
<b>g</b> fs	Forward Transconductance	$V_{GS} = -10 \text{ V}, V_{DS} = -5 \text{ V}$ $V_{DS} = 10 \text{ V}, I_D = 4.5 \text{ A}$	Q2 Q1	-20	14		S
		$V_{DS} = -5 \text{ V}, \text{ I}_{D} = -3 \text{ 5 A}$	Q2		9		
Dvnami	c Characteristics						
Ciss	Input Capacitance	Q1	Q1		650		pF
_		$V_{DS} = 25 V, V_{GS} = 0 V,$	Q2		759		
Coss	Output Capacitance	f = 1.0 MHz Q2	Q1 Q2		80 90		pF
C <sub>rss</sub>	Reverse Transfer	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V},$	Q2 Q1		35		pF
0135	Capacitance	f = 1.0 MHz	Q2		39		μ.
	. Ohene stanistics						
	g Characteristics (Note 2 Turn-On Delay Time		Q1		11	20	200
d(on)	Tum-On Delay Time	$V_{DD} = 30 \text{ V}, \text{ I}_{D} = 1 \text{ A},$	Q2		7	14	ns
r 1	Turn-On Rise Time	$V_{GS} = 10V, R_{GEN} = 6 \Omega$	Q1		8	18	ns
			Q2		10	20	
d(off)	Turn-Off Delay Time	Q2 $V_{DD} = -30 \text{ V}, \text{ I}_{D} = -1 \text{ A},$	Q1 Q2		19 19	35 34	ns
f	Turn-Off Fall Time	$V_{GS} = -10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$	Q2 Q1		6	15	ns
			Q2		12	22	_
ζ <sup>g</sup>	Total Gate Charge		Q1		12.5	18	nC
Q <sub>gs</sub>	Gate-Source Charge	$V_{DS} = 30 \text{ V}, I_D = 4.5 \text{ A}, V_{GS} = 10 \text{ V}$	Q2 Q1		15 2.4	21	nC
~ys	Gato Course Onlarge	Q2	Q2		2.4		
Q <sub>gd</sub>	Gate-Drain Charge	$V_{DS} = -30 \text{ V}, I_D = -3.5 \text{ A}, V_{GS} = -10 \text{ V}$	Q1		2.6		nC
			Q2		3.0		

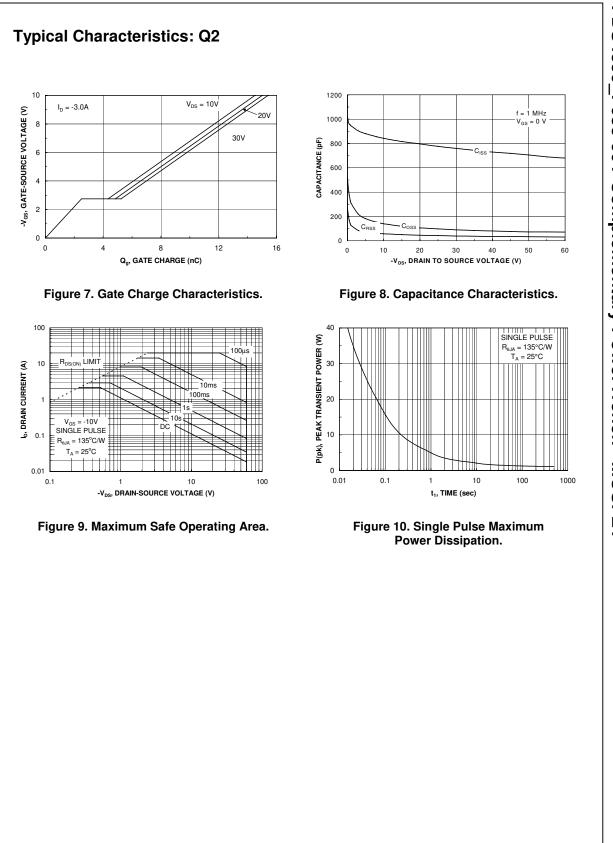
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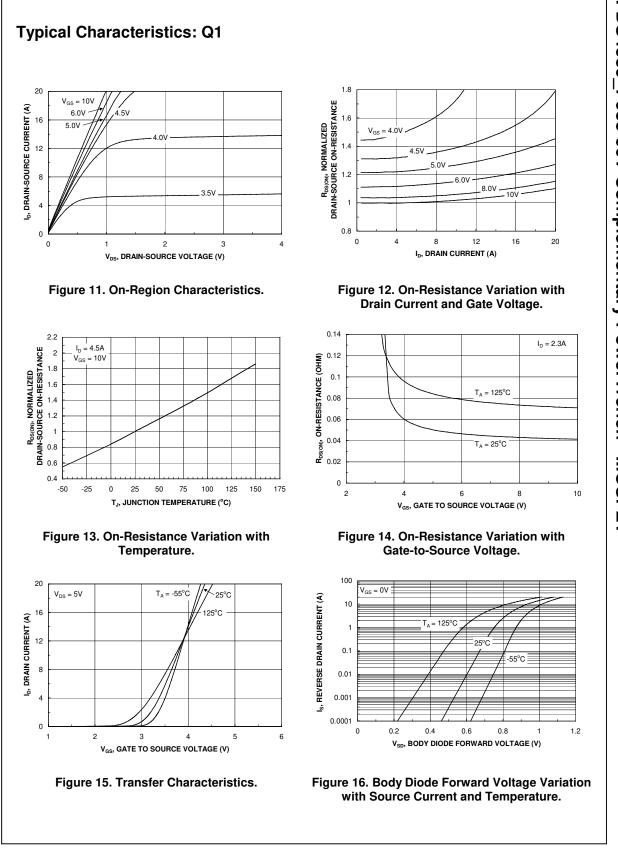
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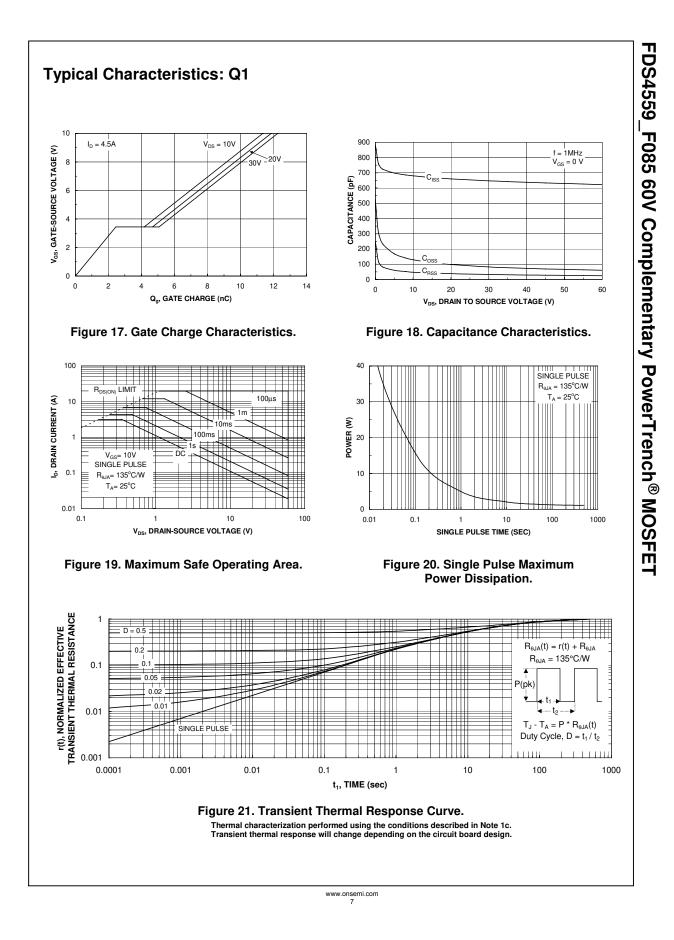


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